

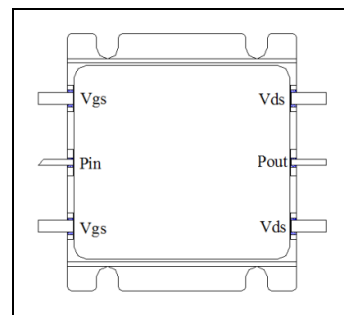


0.5-3.0GHz, 80W, GaN Fully matched PA Module

Description

The XMAH0530-80H3 is a 80-watt, single stage integrated Power Amplifier Module, designed for broad band applications, with frequencies from 0.5 to 3.0GHz. The module is 50 Ω input/output matched and requires minimal external components. It can work at higher voltage up to 32V with increased power capability

The module implements multiple GaN active dice and its matching network within highly compact 30.8*27.4mm metal RF package with excellent capability for heat dissipation.



Vgs = -2.3V, Vds = 28V, Idq = 200mA, CW

Freq(MHz)	Pin(dBm)	Pout(dBm)	Pout(W)	IDS(A)	Gain(dB)	Eff(%)	2 nd Harmonic	3 rd Harmonic
500	38.30	49.80	95.5	6.06	11.50	56.3	-21.0	-12.5
600	37.50	51.70	147.9	9.87	14.20	53.5	-11.5	-14.4
700	37.42	51.60	144.5	11.10	14.18	46.5	-10.3	-14.9
800	36.93	51.20	131.8	10.39	14.27	45.3	-9.7	-16.0
900	37.15	51.10	128.8	9.32	13.95	49.4	-8.0	-12.9
1000	37.50	51.40	138.0	9.64	13.90	51.1	-10.8	-12.4
1100	36.90	51.50	141.3	9.69	14.60	52.1	-12.8	-13.8
1200	37.20	51.30	134.9	9.02	14.10	53.4	-11.8	-13.2
1300	37.10	51.10	128.8	9.00	14.00	51.1	-12.4	-12.3
1400	37.20	50.30	107.2	7.43	13.10	51.5	-7.3	-20.2
1500	38.70	51.20	131.8	9.70	12.50	48.5	-11.0	-27.0
1600	39.05	51.00	125.9	9.37	11.95	48.0	-11.6	-26.0
1700	38.80	51.08	128.2	8.78	12.28	52.2	-13.6	-20.7
1800	37.40	51.20	131.8	8.61	13.80	54.7	-17.6	-16.8
1900	37.00	51.12	129.4	8.21	14.12	56.3	-15.2	-19.0
2000	37.00	50.84	121.3	8.44	13.84	51.3	-15.9	-25.5
2100	39.50	51.40	138.0	9.30	11.90	53.0	-23.3	-31.2
2200	40.40	51.80	151.4	10.63	11.40	50.9	-26.5	-29.2
2300	40.30	51.85	153.1	10.48	11.55	52.2	-27.4	-27.8
2400	40.30	51.30	134.9	9.21	11.00	52.3	-24.4	-27.3
2500	40.00	50.38	109.1	7.25	10.38	53.8	-19.5	-38.0
2600	39.65	49.50	89.1	6.30	9.85	50.5	-13.6	-36.7
2700	38.60	49.33	85.7	6.00	10.73	51.0	-11.7	-32.3
2800	37.12	49.60	91.2	6.20	12.48	52.5	-14.0	-39.0
2900	38.20	49.90	97.7	6.83	11.70	51.1	-18.4	-36.0
3000	40.50	50.00	100.0	7.37	9.50	48.5	-24.0	-28.0



Product Features

- Operating Frequency Range: 0.5-3.0GHz
- Operating Drain Voltage(Recommended): +28 V (up to 32V with power increased)
- 50 Ω Input/Output (External DC block capacitor needed)
- $P_{sat} \geq 49$ dBm (CW)
- Small signal gain:>13dB, Power gain:>10dB
- Minimum efficiency:>45%
- 30.8*27.4 mm metal RF package
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

Applications

- Ultra Broadband Amplifiers, typically 0.8-2.5GHz, 1-2GHz,2-3GHz
- L band power amplifier, typically 960-1215MHz, 1200-1400MHz.1400-1600MHz
- Test Instrumentation
- EMC Amplifier Drivers
- 2-way Radios

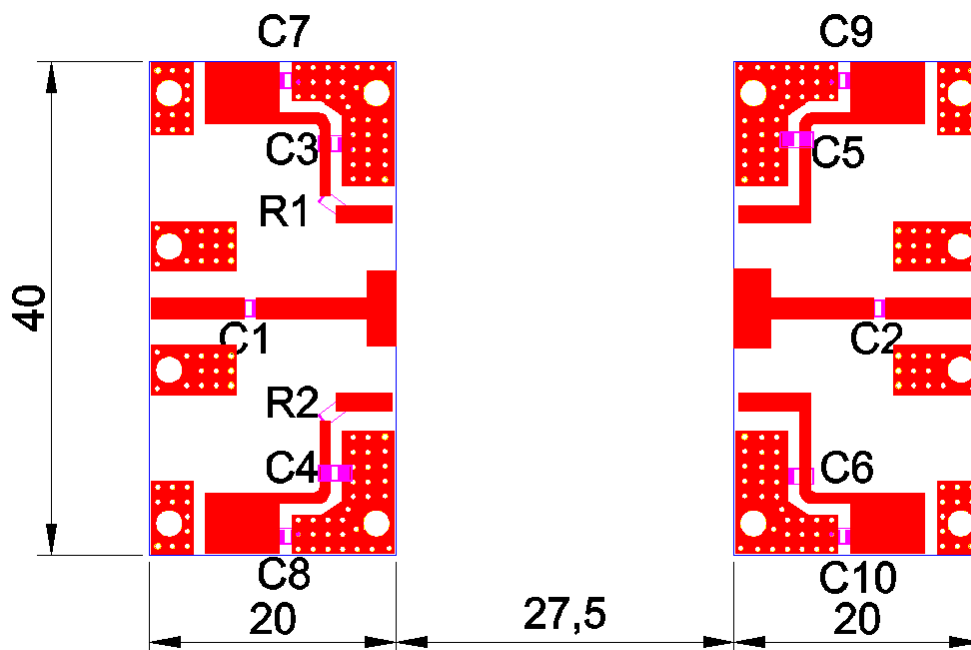
Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain--Source Voltage	V_{DS}	150	Vdc
Gate--Source Voltage	V_{GS}	-10 to +2	Vdc
Operating Voltage	V_{DD}	+32	Vdc
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}C$
Case Operating Temperature	T_c	+150	$^{\circ}C$
Operating Junction Temperature	T_j	+225	$^{\circ}C$

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case $T_c = 25^{\circ}C$, $P_{out} = 80W$, FEA	$R_{\theta JC}$	1.2	$^{\circ}C/W$

Typical application circuit



Component	Description	Suggested Manufacturer / Series Number
C1 C3 C4 C5 C6	6.8 pF	MQ200805
C2	6.8 pF x 2	MQ301111
C7 C8 C9 C10	10 uF	TDK
R1	10 Ohm	1206 SMD Resistor
PCB	30Mil Rogers 4350	Rogers

TYPICAL CHARACTERISTICS

Figure 1. Network analyzer output S11/S21 (Pin=0dBm, Idq=200mA)

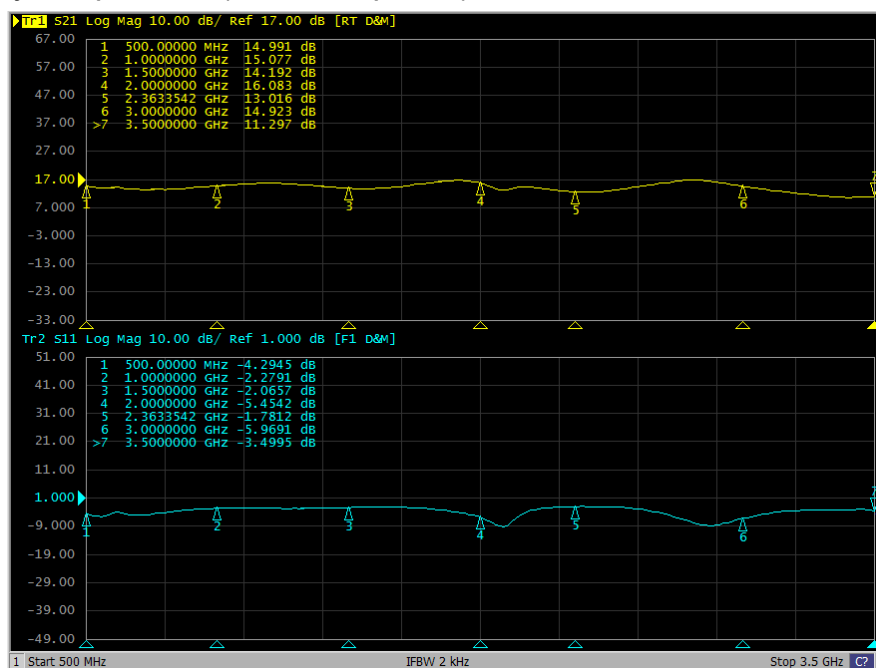




Figure 3. CW Psat, Eff and Power Gain, Eff, Drain current, Harmonics Vs Frequency across the band

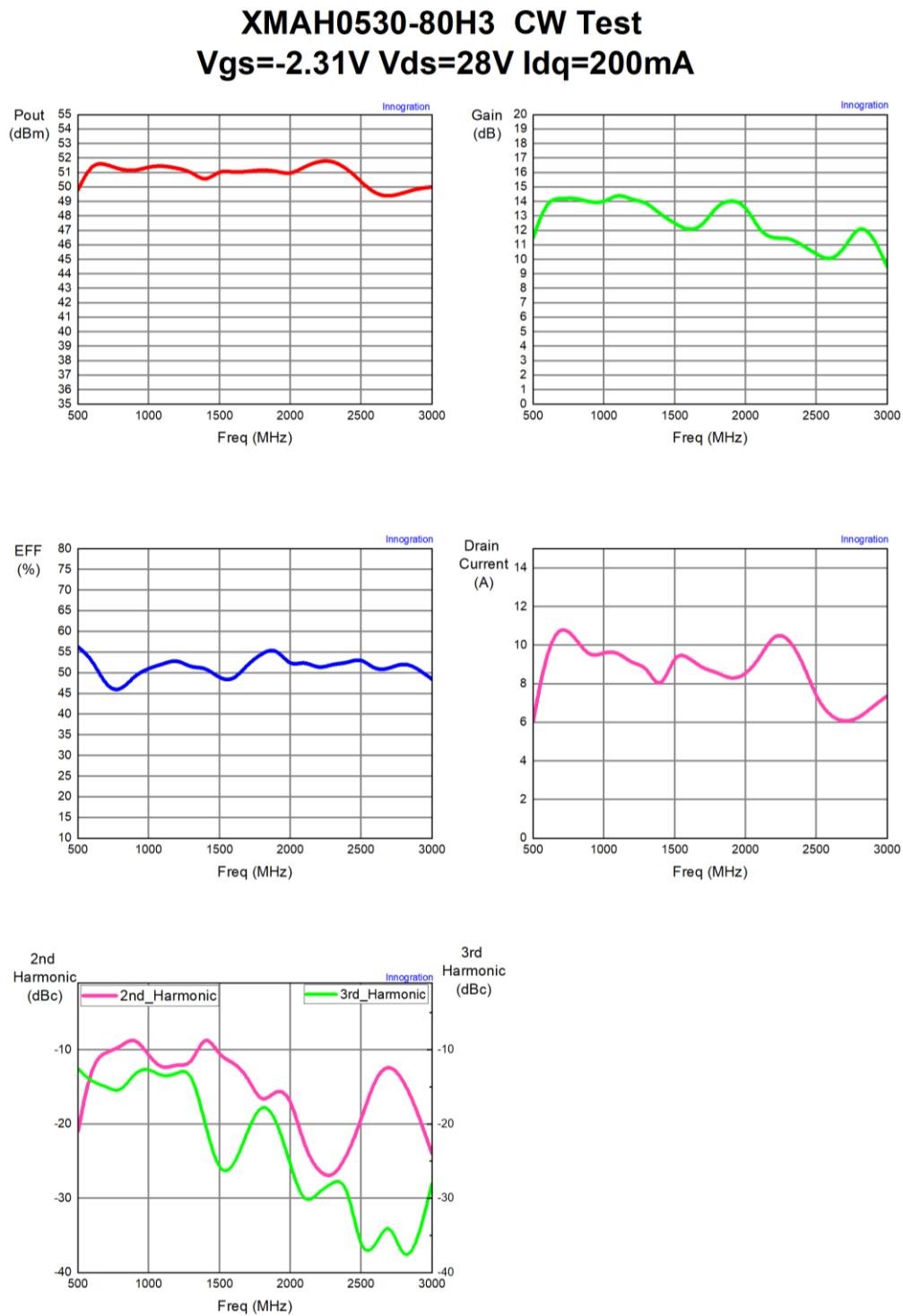
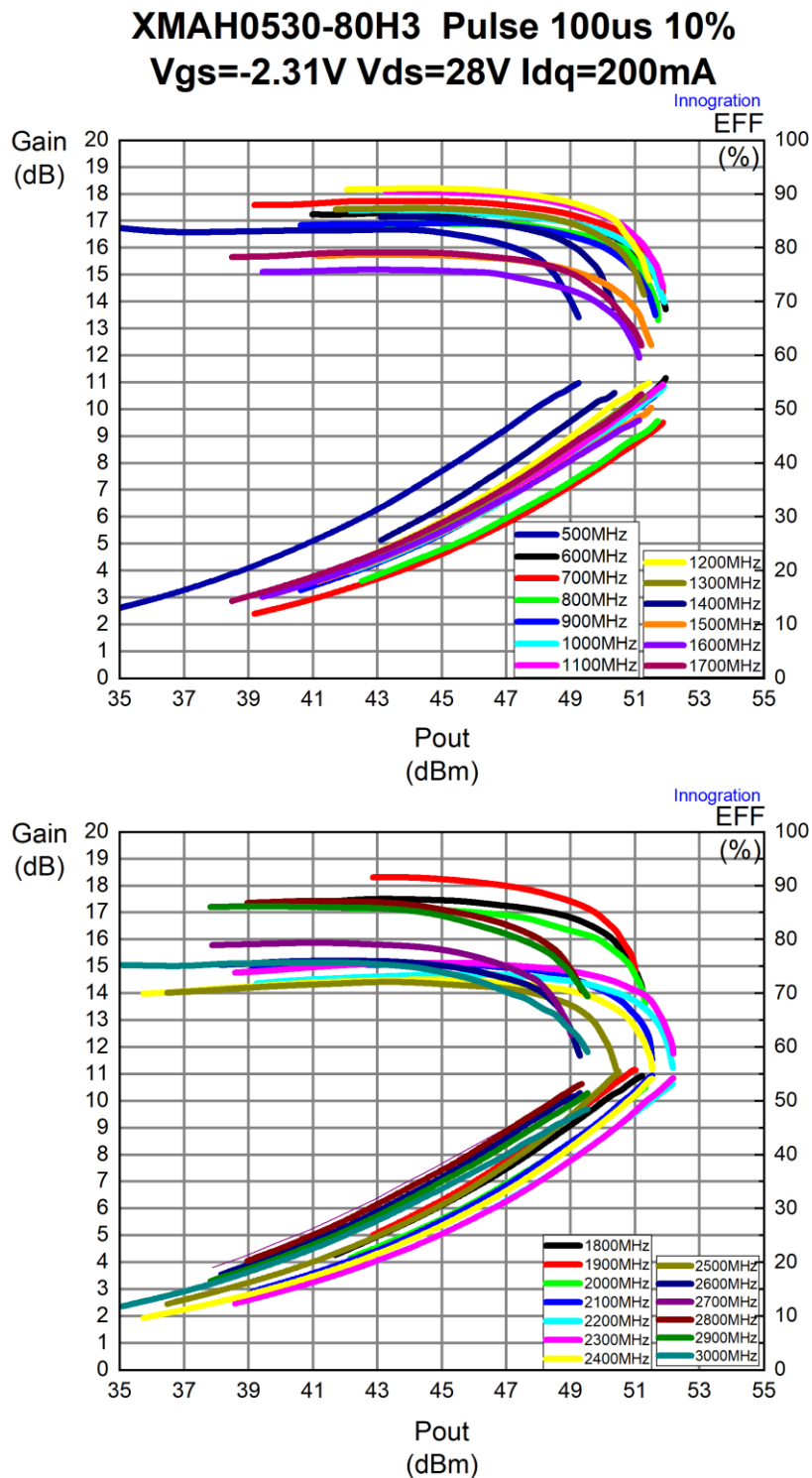


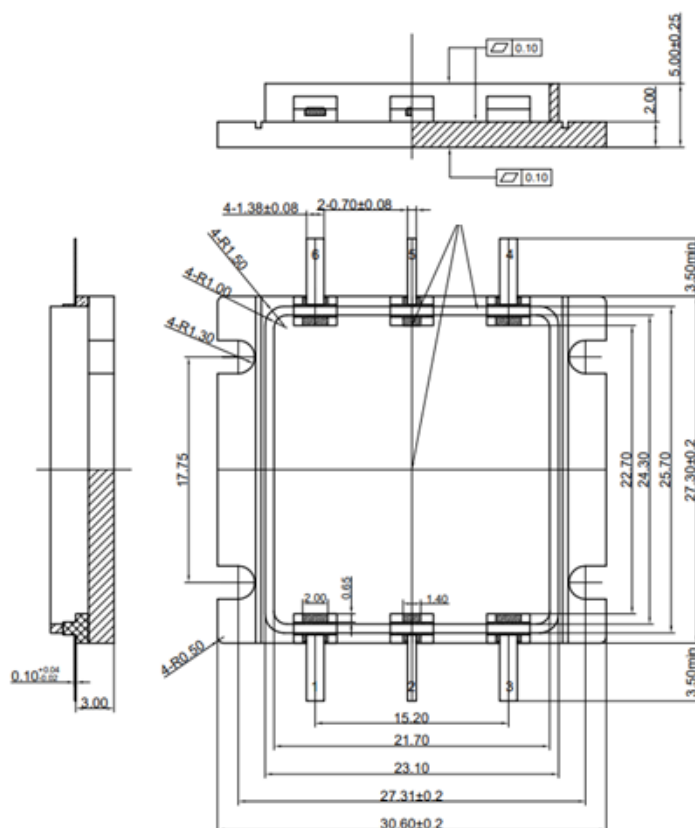


Figure 4. Pulsed CW Psat, Eff and Power Gain, Eff, Vs Frequency across the band





Package Dimensions (Unit:mm)



Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2025/10/24	Rev 1.0	Preliminary Datasheet

Application data based on JF-25-33

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